NSN 5961-01-353-5526

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-353-5526 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.063 inches **Overall Height:** 0.008 inches **Overall Width:** 0.063 inches **Function For Which Designed:** Rectifier **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 working peak reverse voltage and 150.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 125.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 1 bonding pad and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No